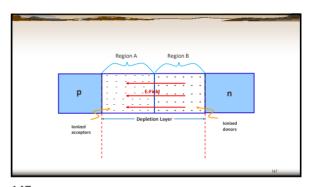
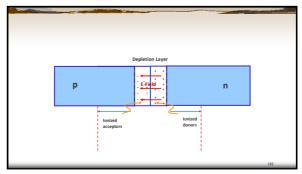


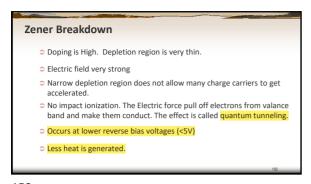
The Zener Diode 1) Some Zener diodes use Zener breakdown (< 5V) 2) Some Zener diodes use Avalanche breakdown (>5V) 3) Neither Zener nor avalanche breakdown are inherently destructive 4) The heat generated by the large current flowing can cause damage in both cases.

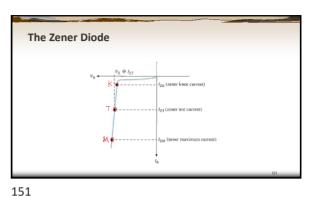


146 147

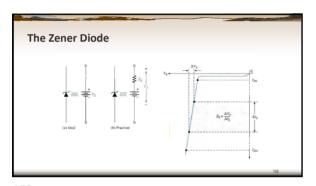
Avalanche Breakdown Doping is small. Depletion region is wide. ⇒ The minority charge carriers get accelerated in this depletion region and gain kinetic energy. □ They knock off, other electrons from the valence Avalanche effect caused by Impact Ionization process. Occurs at higher reverse bias voltages (>5V) More heat is generated.

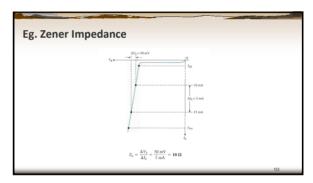




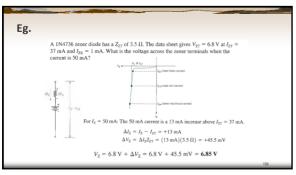


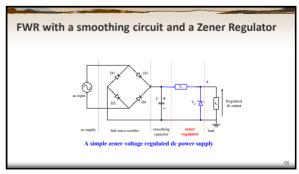
150 15

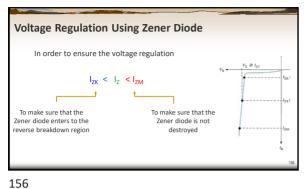


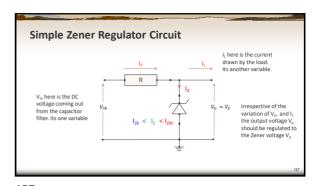


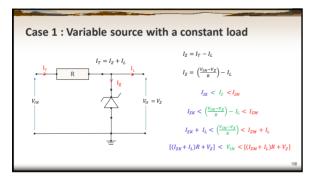
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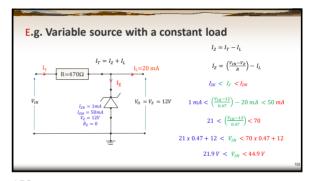


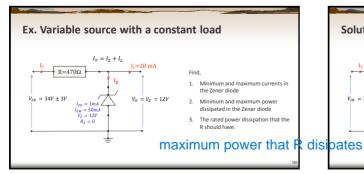


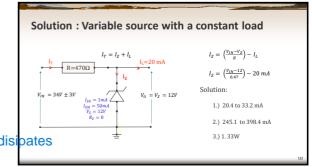


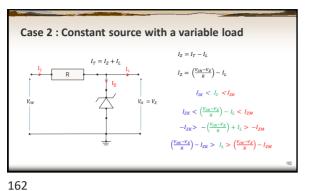


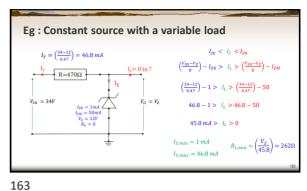


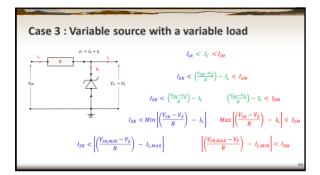


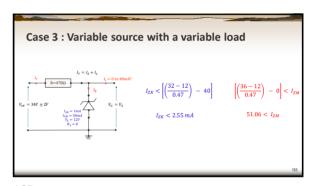


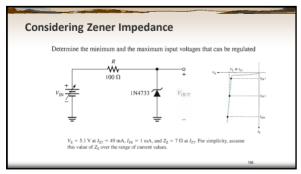


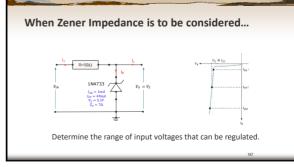


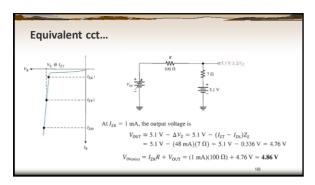






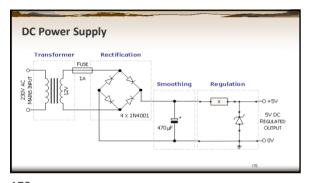


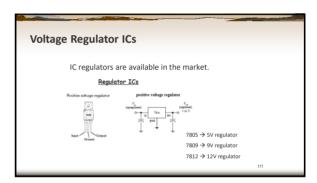




Equivalent cct... $I_{\rm EM} = \frac{P_{\rm O(max)}}{V_{\rm Z}} = \frac{1~{\rm W}}{5.1~{\rm V}} = 196~{\rm mA}$ At $I_{\rm Zhe}$ the output voltage is $V_{\rm OCT} \simeq 5.1~{\rm V} + \Delta V_{\rm Z} = 5.1~{\rm V} + (I_{\rm Zh} - I_{\rm ZT})Z_{\rm Z}$ $= 5.1~{\rm V} + (147~{\rm mA})(7~\Omega) \simeq 5.1~{\rm V} + 1.03~{\rm V} = 6.13~{\rm V}$ Therefore, $V_{\rm D(max)} = I_{\rm Zh}R + V_{\rm OCT} = (196~{\rm mA})(100~\Omega) + 6.13~{\rm V} = 25.7~{\rm V}$

168 169





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